E ect of Hydrostatic Pressure on the Kondo E ect in the Heavy

Ferm ion System Yb₂Fe₃Si₅

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Abstract

W e report the e ect of hydrostatic pressure on the resistivity of the heavy ferm ion K ondo lattice com pound $Y b_2 Fe_3 Si_5$ in the tem perature range 2-300 K and in pressures upto 10 K bar. At am bient pressure the resistivity shows a prom inent K ondo e ect. The K ondo m inim um shifts from 22.5 K at am bient pressure to 19.2 K at a pressure of 10 K bar. The depth of the K ondo m inim um also progressively decreases with pressure. These results suggest a possible weakening of the K ondo e ect with the application of pressure.

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C om pounds of the series $R_2Fe_3Si_5$ are known to show unusual superconducting and m agnetic properties [1{4]. B oth Tm $_2Fe_3Si_5$ and $Lu_2Fe_3Si_5$ of this series undergo superconducting transitions at low tem peratures. W hile $Lu_2Fe_3Si_5$ has the highest T_c (= 6 K) for an Fe containing com pound, Tm $_2Fe_3Si_5$ is the rst reentrant superconductor where the superconductivity at about 1.6 K is destroyed by the onset of antiferrom agnetic order at 1 K.

G iven that both the Tm and Lu samples of the series show superconductivity at low tem – peratures, the absence of superconductivity in Yb₂Fe₃Si₅ is puzzling. Our recent work [5] on high quality single-phase polycrystalline samples of Yb₂Fe₃Si₅ revealed the presence of strong hybridization (= 500 m J/Yb m ol K 2) and K ondo e ect below 25 K in this sam – ple. It is known that K ondo interactions can strongly suppress superconductivity. For Ce com pounds, pressure is known to enhance the K ondo tem perature T_K . Yb being the hole analog of Ce (Ce has one 4f electron while Yb has one 4f hole), the T_K for Yb system s can be expected to go down on the application of pressure. Thus, we have studied the e ect of the application of hydrostatic pressure on the K ondo e ect. Our aim is to understand the absence and possibility of inducing superconductivity in this com pound by the application of pressure.

II.EXPERIM ENTAL DETAILS

Polycrystalline sam ples of Y b_2 Fe₃Si₅ were prepared by the closed crucible m ethod described in our earlier work [5]. Powder X -ray di raction m easurem ents con m ed the structure and the absence of in purity phases.

The dc resistivity m easurem ents were performed on a bar shaped sample of Y b_2 Fe₃Si₅ using contacts made with silver paste. The sample is placed inside a te on tube led with a hydrostatic pressure medium (D aphne oil). This te on tude is kept inside a Cu-Be cell of the piston-clamp type which can be pressurised upto 14 K bar. The resistivity was measured

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using an ac resistance bridge (Linear Research Inc., USA) from 2 to 300 K.

III.RESULTS AND DISCUSSION

In glwe show the ambient pressure resistivity (T) for $Yb_2Fe_3Si_5$ in the tem perature range 2-300 K. The resistance decreases slow ly as we cool down from 300 K untill about 150 K after which it starts to drop m ore rapidly indicative of crystal eld e ects. The inset (a) shows the resitivity between 0.4 and 2.5 K. A distinct change of slope at 1.7 K m arks the onset of the anti-ferrom agnetic order in the sam ple. This is consistent with the resistivity, susceptibility and heat capacity data on our earlier sam ple [5].

The inset (b) in g.1 shows the data between 2-50 K on an expanded scale to emphasize the presence of the K ondo e ect with a minimum in resistivity at 22.5 K after which the resistance starts to increase again until it reaches a maximum at around 6 K after which it sharply decreases again due to coherent scattering. W e will call the maximum in the resistivity as the coherence peak and the tem perature at which it occurs as the coherence tem perature T_{coh} to make it easy to compare the data for di erent pressures.

The g. 2 shows the resistivity of $Yb_2Fe_3Si_5$ for various pressures. We have plotted R (T)/R (300 K) to be able to make qualitative comparisons between the data for di erent pressures. The panel I shows the normalized resistance between 2-300 K for applied pressure values P = 0, 3.5, 5, 8.5 and 10 K bar. P = 0 K bar actually means the ambient pressure data. At present the values of the pressures are taken at room temperature. It must be noted that the actual pressure at low temperatures will be slightly reduced. From panel I it is evident that the data for all pressures fall on top of each other between 100-300 K. It can be safely said that the pressure has no appreciable e ect on the lattice contribution to the transport properties. The data for di erent pressures begin to deviate only below 50 K where the K ondo e ect is dom inant.

In panel II we show the data between 2-50 K on an expanded scale to highlight the e ect of pressure on the K ondo e ect. It can be seen that the K ondo m inimum shifts to

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lower tem peratures on the application of pressure and the depth of the K ondo m in im um also progressively decreases with increasing pressure.

To make a quantitative comparison we have listed in table 1 the values of the applied pressure $P, T_{M \text{ IN}}$ at which the K ondo m in imum occurs, T_{COH} at which the coherence peak occurs and $R_{TCOH}/R_{TM \text{ IN}}$ as a measure of the depth of the K ondo m in imum.

It can be seen from the second column listing the values of $T_{M \ IN}$ that as we increase the applied pressure, the K ondo m inimum shifts to lower temperatures. Also, from the fourth column in which we list values of $R_{TCOH}/R_{TM \ IN}$ as an estimate of the depth of the K ondo bow l, it is evident that the K ondo bow l becomes progressively shallower on increasing pressure. There is no appreciable change in the temperature T_{COH} of the onset of the coherence peak.

IV . C O N C LU S IO N

We have studied the pressure dependence of the resistivity of the heavy ferm ion K ondo lattice compound $Y b_2 Fe_3 Si_5$ to look at the e ect of hydrostatic pressure on the K ondo interactions in this compound and in Y b compounds in general.

We nd that the temperature $T_{M IN}$ at which the Kondo minimum occurs, reduces from about 22.5 K at ambient pressure to 19.2 K at a pressure of 10 K bar. We have also seen a monotonic reduction of the depth of the Kondo minimum with increasing pressure. Taken together we can safely say that the application of pressure has the elect of weakening the Kondo elect in the compound $Yb_2Fe_3Si_5$. Further studies are in progress to see whether we can induce superconductivity in this compound via the suppression of the Kondo elect with the application of pressure.

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FIGURES

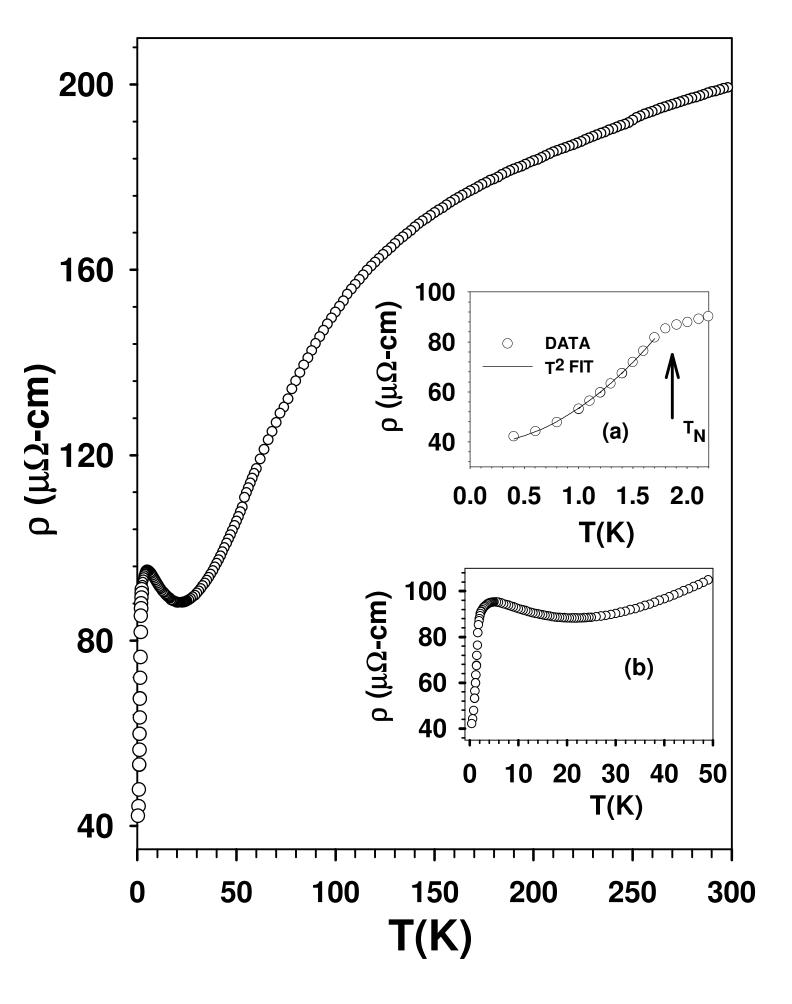
FIG.1. Tem perature dependence of the resistivity () of $Yb_2Fe_3Si_5$ from 0.4 to 300 K. The inset (a) shows the data from 0.4 to 2.5 K on an expanded scale. A de nite change of slope below 1.7 K marks the onset of the anti-ferrom agnetic ordering. The solid line is the t to a T^2 law. The inset (b) shows data upto 50 K. A distinct K ondo e ect is visible with a minimum in at 22.5 K and a drop below 6 K due to coherence.

FIG.2. Temperature dependence of the resistivity at various pressures, normalized to it's room temperature value. The panel I shows the data between 2-300 K. It is clear that there is no signi cant e ect of pressure on the lattice part of the resistivity. The panel II shows the data between 2-50 K on an expanded scale to show more clearly the e ect of pressure on the K ondo e ect.

TABLES

P (K bar)	T _{M IN}	Т _{сон}	$R_{TCOH} / R_{TM IN}$	
0	22.5	4.68	1.063	
35	21.3	4.74	1.059	
5	20.8	4.68	1.056	
8.5	20.1	4.72	1.053	
10	192	4.75	1.049	

TABLE I. Param eters obtained from the resistivity data of Y $b_2 Fe_3 Si_5$ under pressure.



Yb₂Fe₃Si₅

